2SC3390

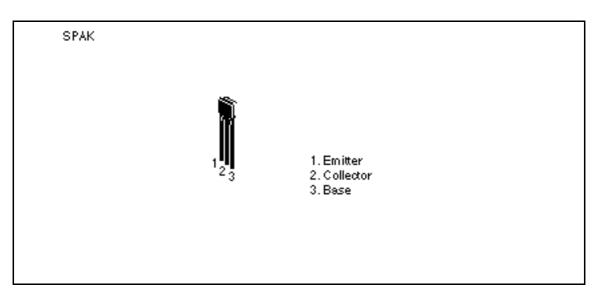
Silicon NPN Epitaxial

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Application

- Low frequency low noise amplifier
- HF amplifier

Outline



Absolute Maximum Ratings (Ta = 25° C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	55	V
Collector to emitter voltage	V _{CEO}	50	V
Emitter to base voltage	V _{EBO}	5	V
Collector current	I _c	100	mA
Collector power dissipation	P _c	300	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C



2SC3390

Electrical Characteristics (Ta = 25° C)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	55	_	_	V	$I_{c} = 10 \ \mu A, I_{e} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	50	_	_	V	$I_c = 1 \text{ mA}, R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	V	$I_{\rm E} = 10 \ \mu A, \ I_{\rm C} = 0$
Collector cutoff current	I _{CBO}	—	—	0.5	μA	$V_{CB} = 18 \text{ V}, \text{ I}_{E} = 0$
Emitter cutoff current	I _{EBO}	_	_	0.5	μA	$V_{EB} = 2 V, I_{C} = 0$
DC current transfer ratio	$h_{\rm FE}^{*1}$	100	_	320		$V_{ce} = 12 \text{ V}, \text{ I}_{c} = 2 \text{ mA}$
Base to emitter voltage	V_{BE}	_	_	0.75	V	$V_{ce} = 12 \text{ V}, \text{ I}_{c} = 2 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	0.2	V	$I_{c} = 10 \text{ mA}, I_{B} = 1 \text{ mA}$
Gain bandwidth product	f_{T}	_	200	_	MHz	$V_{ce} = 12 \text{ V}, \text{ I}_{c} = 2 \text{ mA}$
Collector output capacitance	Cob	_	_	3.5	pF	$V_{_{CB}} = 10 \text{ V}, \text{ I}_{_{E}} = 0, \text{ f} = 1 \text{ MHz}$
Noise figure	NF	_	1.0	5.0	dB	$\label{eq:V_ce} \begin{split} V_{ce} &= 6 \ V, \ I_c = 0.1 \ mA, \\ R_g &= 1 \ k \ , \ f = 1 \ kHz \end{split}$

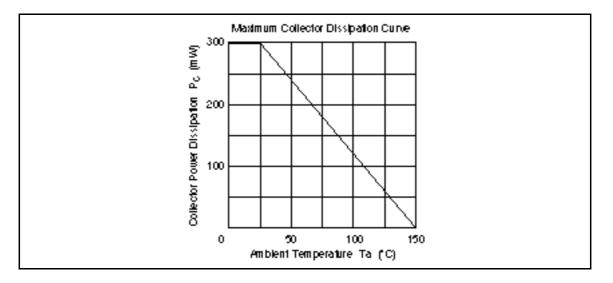
Note: 1. The 2SC3390 is grouped by h_{FE} as follows.

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В
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100 to 200 160 to 320

С

See characteristic curves of 2SC458(LG).



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Hitachi, Ltd.

Semiconductor & IC DV. Neppon Bidg, 2-5-2, Ohte-mach, Chiyoda-ku, Tokyo 100, Japan Tet Tokyo (03, 3270-2111 Fax (03, 3270-5109

For Author in forms ion write to : Hischi America, Ud Semiconductor & IC DV. 2000 Sierre Point Perlavey Briebene, CA. 94005-4835 U S.A. Tet 415-589-8300 Fax 415-583-4207

Hischi Burope GmbH Bectronic Components Group Cartishertsi Burope Danscher Straße 3 D-85522 Feldkirchen Minchen Tet 089-9 94 80-0 Fex: 089-9 29 30 00 Hitschi Burope Ltd. Bectronic Components Div. Northern Burope Headquerters Whitsbrock Ferk Lower Cock hem Roed hitidenheed Berkshire SLGSYÅ United Kingdom Tet 0525-585000 Fet: 0525-778322 Hitschi Asia Pta. Ltd 45 Collyer Quay \$20-00 Hitschi Towar Singspore 0404 Tet 535-2400 Fex 535-4533

Hitschi Asia (Hong Kong) Ltd. Unit 705, North Towar, World Finance Cantre, Herbour City, Carton Road Taim She Teut, Kowloon Hong Kong Tet 27350218 Fax: 27350218

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